



Data Sheet

Trans MOSFET N/P-CH 30V 3.9A/3.5A 8-Pin SOIC N T/R

Manufacturers ON Semiconductor, LLC

Package/Case SOP-8

Product Type Transistors

RoHS Green

Lifecycle



Images are for reference only

Please submit RFQ for SI4532DY or **Email to us: sales@ovaga.com** We will contact you in 12 hours.

RFQ

General Description

These dual N- and P-Channel enhancement mode power field effect transistors are produced using Fairchild's proprietary, high cell density, DMOS technology. This very high density process is especially tailored to minimize on-state resistance and provide superior switching performance. These devices are particularly suited for low voltage applications such as notebook computer power management and other battery powered circuits where fast switching, low in-line power loss, and resistance to transients are needed.

Features Application

P-Channel -3.5 A, -30 V = -10 V = -4.5 V

ONSEMI

N-Channel 3.9 A, 30V = 10V = 4.5V

High power and current handling capability in a widely used surface mount package

High density cell design for extremely low RDS(ON)



Related Products



SI4435DY

ON Semiconductor, LLC SOIC-8



MJE172

ON Semiconductor, LLC TO-126



KSC2690AYSTU

ON Semiconductor, LLC TO-126



<u>NTR4003NT3G</u>

ON Semiconductor, LLC SOT-23



D45H11G

ON Semiconductor, LLC TO-220



MJE350G

ON Semiconductor, LLC TO-126



 $\underline{\text{2SC4027S-TL-E}}$

ON Semiconductor, LLC TO-252



2N3904TA

ON Semiconductor, LLC TO-92-3 Kinked Lead